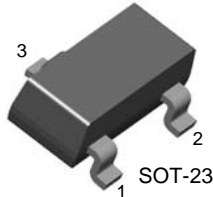


MMBT5770 NPN RF Transistor

- This device is designed for use as RF amplifiers, oscillators and multipliers with collector currents in the 1.0 mA to 30 mA range.
- Sourced from process 43.



1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	30	V
V_{CEO}	Collector-Emitter Voltage	15	V
V_{EBO}	Emitter-Base Voltage	4.5	V
I_C	Collector Current - Continuous	10	mA
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$

Thermal Characteristics $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Max.	Units
P_D	Total Device Dissipation Derate above 25°C	225 1.8	mW mW/ $^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	556	$^\circ\text{C}/\text{W}$

* Device mounted on FR-4PCB $1.6'' \times 1.6'' \times 0.06''$.

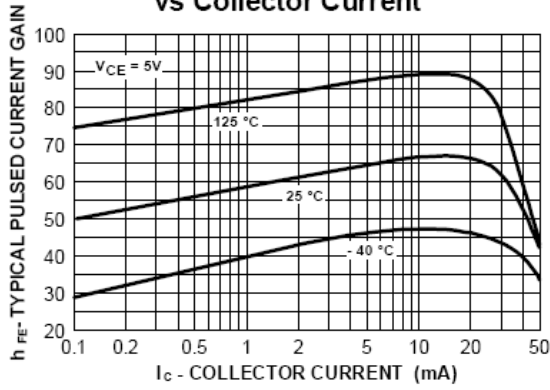
Electrical Characteristics $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characteristics					
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 1.0 \mu\text{A}, I_E = 0$	30		V
$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage*	$I_C = 3.0 \text{mA}, I_B = 0$	15		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10 \mu\text{A}, I_C = 0$	3		V
I_{CBO}	Collector-Cutoff Current	$V_{CB} = 15 \text{V}, I_E = 0$		50	nA
On Characteristics *					
h_{FE}	DC Current Gain	$V_{CE} = 1.0\text{V}, I_C = 3.0\text{mA}$	30		
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 10\text{mA}, I_B = 1.0\text{mA}$		0.4	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 10\text{mA}, I_B = 1.0\text{mA}$		1.0	V
Small Signal Characteristics					
f_T	Current Gain Bandwidth Product	$I_C = 4.0\text{mA}, V_{CE} = 10\text{V}, f = 100\text{MHz}$	600		MHz

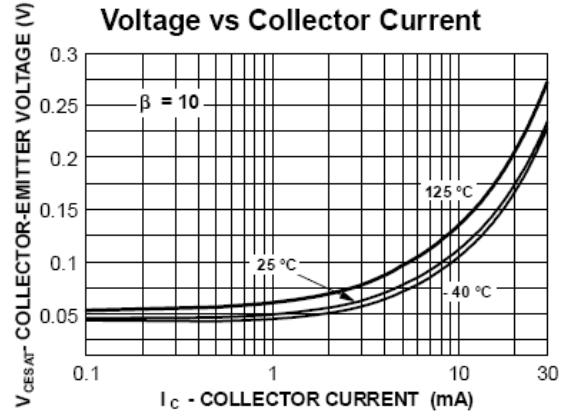
* Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2\%$

Typical Characteristics

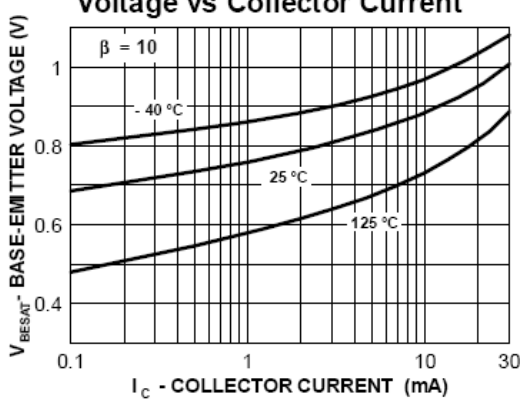
Typical Pulsed Current Gain vs Collector Current



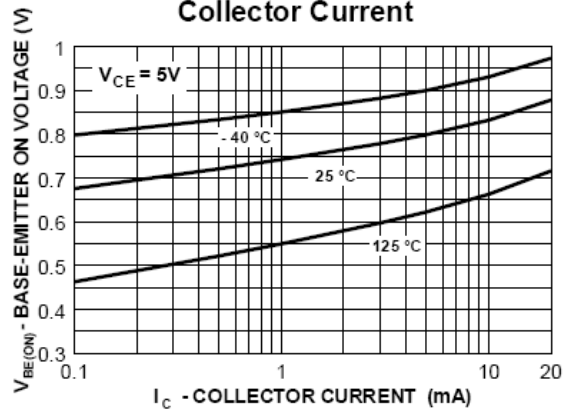
Collector-Emitter Saturation Voltage vs Collector Current



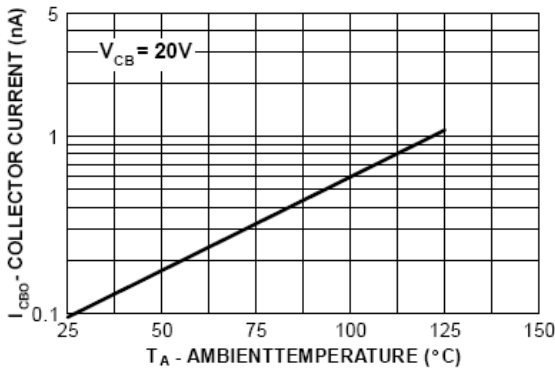
Base-Emitter Saturation Voltage vs Collector Current



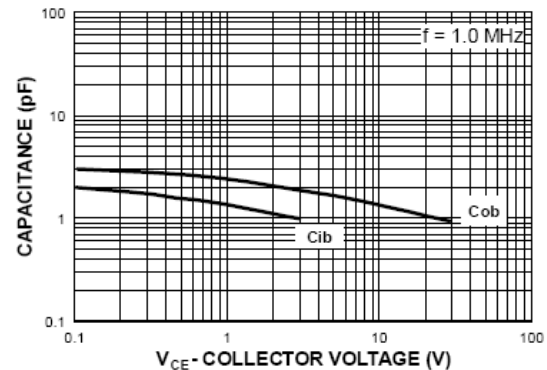
Base-Emitter ON Voltage vs Collector Current



Collector-Cutoff Current vs Ambient Temperature

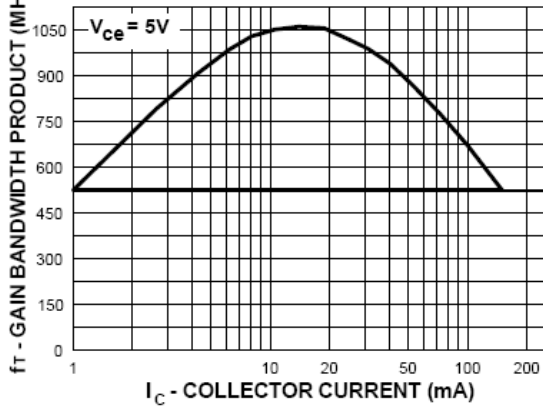


Input and Output Capacitance vs Reverse Voltage

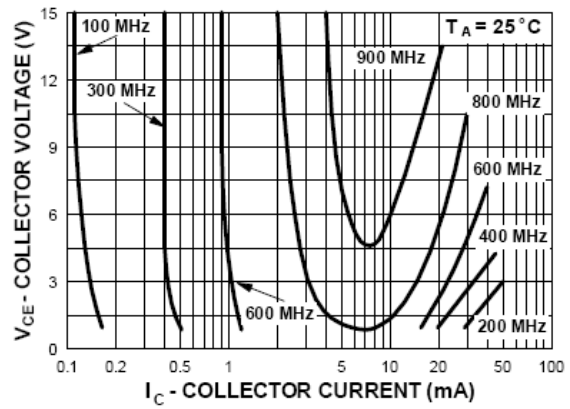


Typical Characteristics (continued)

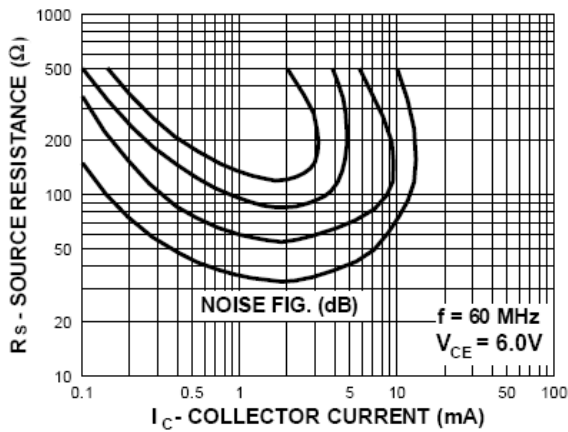
Gain Bandwidth Product vs Collector Current



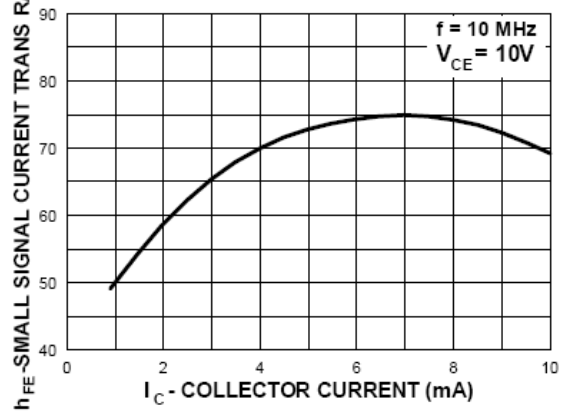
Contours of Constant Gain Bandwidth Product (f_T)



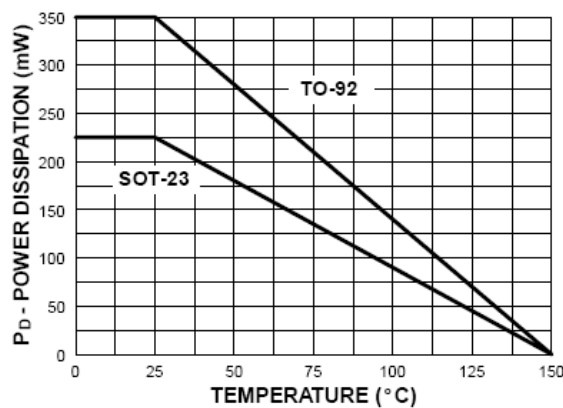
Contours of Constant Noise Figure



Small Signal Current Gain vs Collector Current

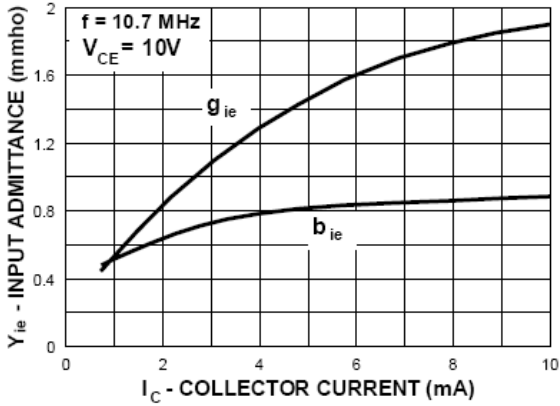


Power Dissipation vs Ambient Temperature

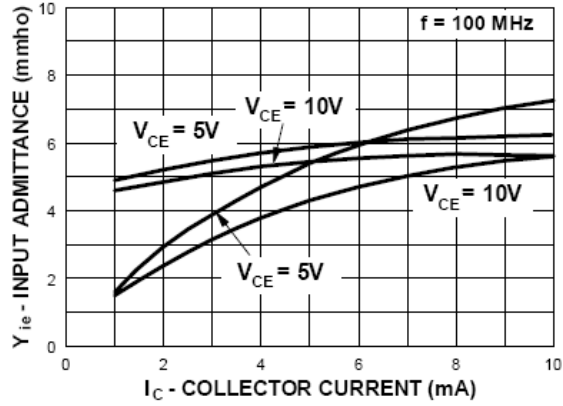


Typical Characteristics (continued)

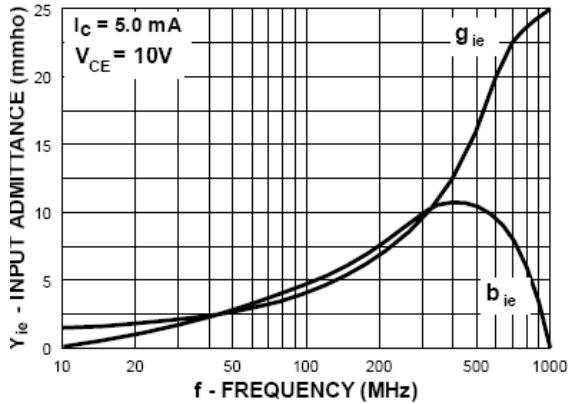
Input Admittance vs Collector Current-Output Short Circuit



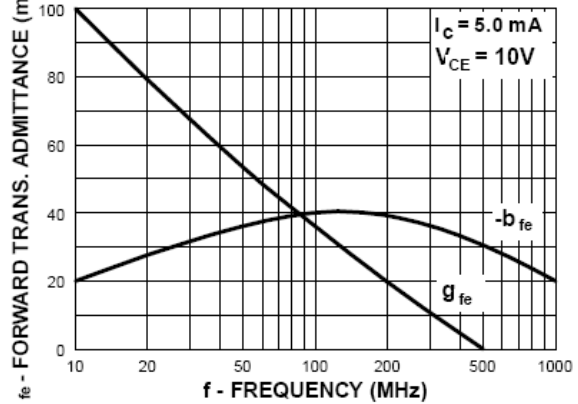
Input Admittance vs Collector Current-Output Short Circuit



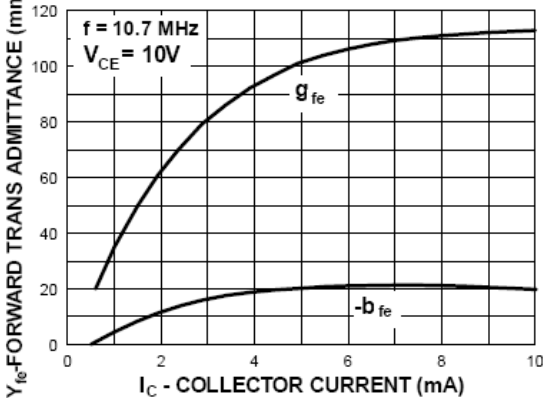
Input Admittance vs Frequency-Output Short Circuit



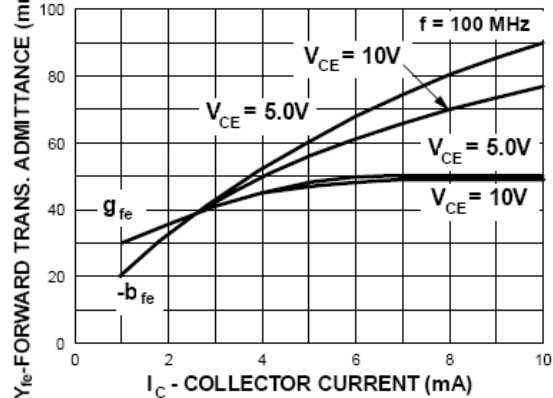
Forward Transfer Admittance vs Frequency-Output Open Circuit



Forward Trans. Admittance vs Collector Current-Output Short Circuit

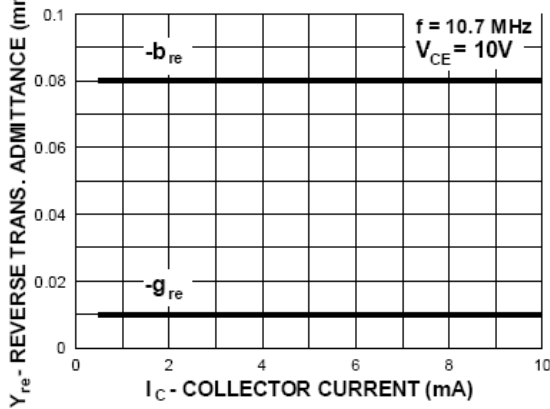


Forward Trans. Admittance vs Collector Current-Output Short Circuit

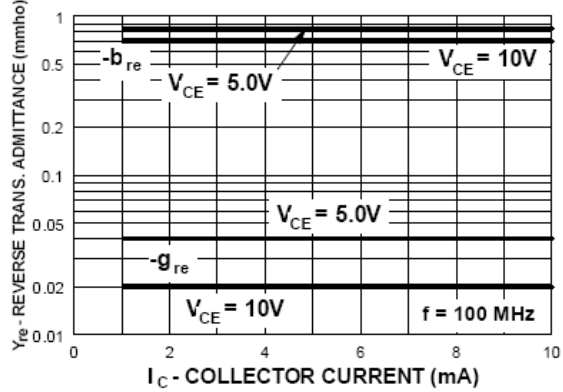


Typical Characteristics (continued)

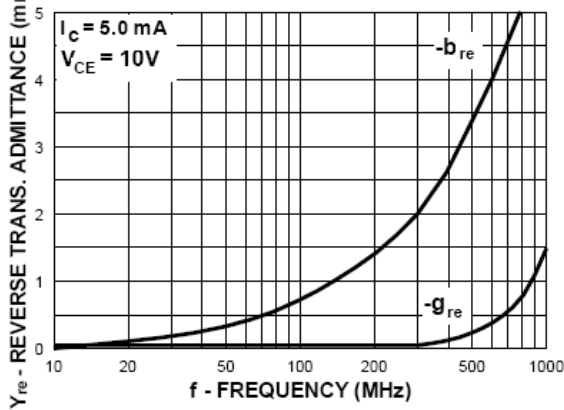
Reverse Transfer Admittance vs Collector Current-Input Short Circuit



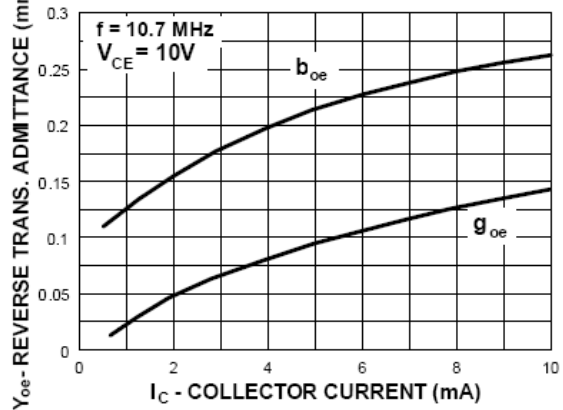
Reverse Transfer Admittance vs Collector Current-Input Short Circuit



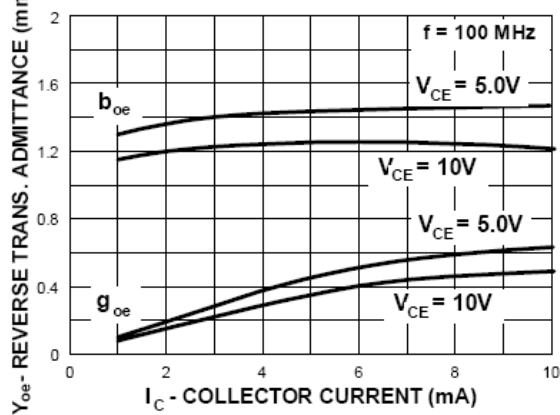
Reverse Transfer Admittance vs Frequency-Input Short Circuit



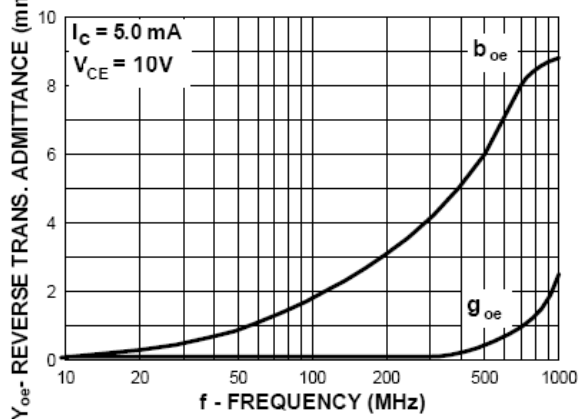
Output Admittance vs Collector Current-Input Short Circuit



Output Admittance vs Collector Current-Input Short Circuit




Output Admittance vs Frequency-Input Short Circuit





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